

SANYO Semiconductors DATA SHEET

2SJ646 — General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-8	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-32	Α
Allowable Power Dissipation	PD		1	W
		Tc=25°C	15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.1-24
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-4A	3.3	5.5		S
Static Drain-to-Source On-State Resistance	RDS(on)1	I _D =-4A, V _G S=-10V		58	75	mΩ
	RDS(on)2	ID=-2A, VGS=-4.5V		97	136	$m\Omega$
	RDS(on)3	I _D =-2A, V _G S=-4V		110	154	mΩ
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		510		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		115		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		78		pF

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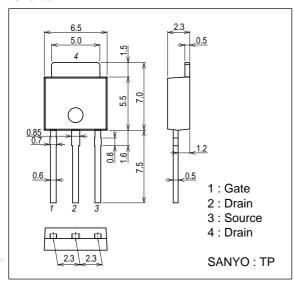
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	td(on)	See specified Test Circuit.		11		ns
Rise Time	t _r	See specified Test Circuit.		40		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		40		ns
Fall Time	tf	See specified Test Circuit.		30		ns
Total Gate Charge	Qg	V _{DS} =-10V, V _{GS} =-10V, I _D =-8A		11		nC
Gate-to-Source Charge	Qgs	V _D S=-10V, V _G S=-10V, I _D =-8A		2.4		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-10V, V _{GS} =-10V, I _D =-8A		1.7		nC
Diode Forward Voltage	V _{SD}	I _S =-8A, V _{GS} =0V		-1.0	-1.2	V

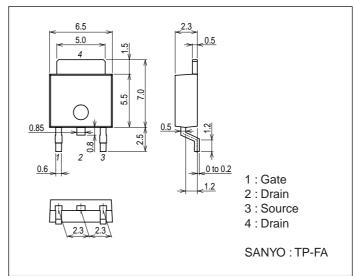
Package Dimensions

unit : mm 7518-004

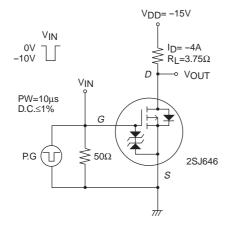


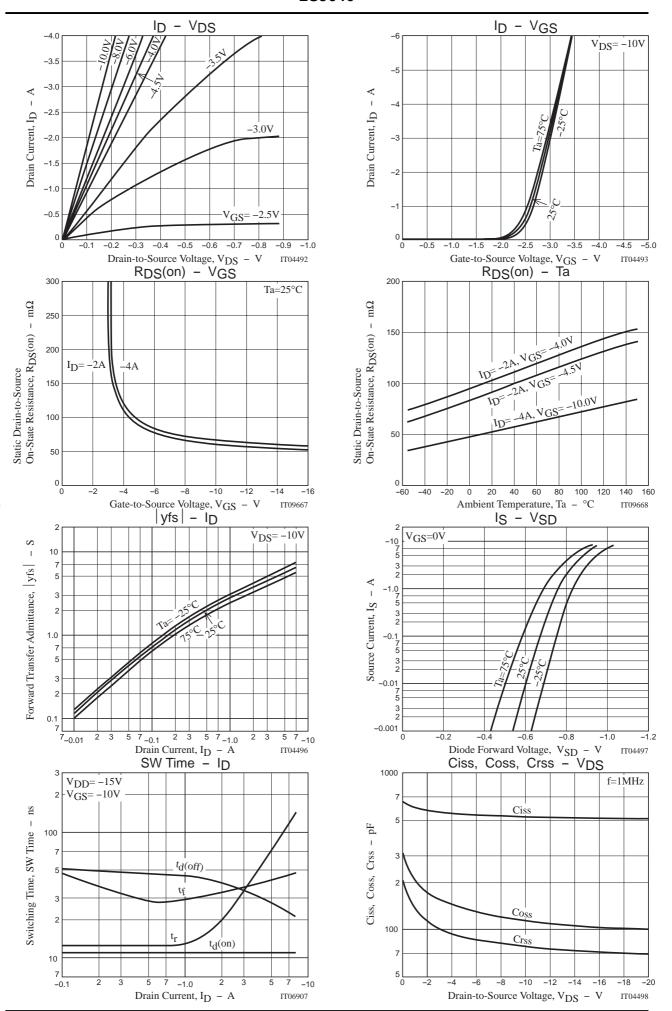
Package Dimensions

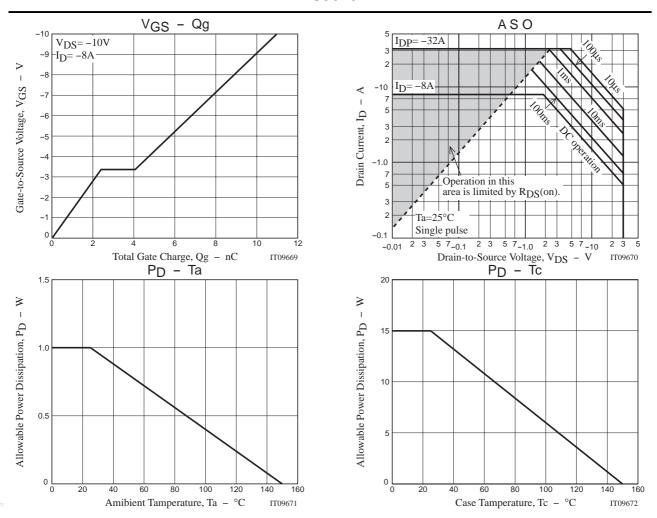
unit : mm 7003-004



Switching Time Test Circuit







Note on usage: Since the 2SJ646 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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